SN54LVC574A . . . J OR W PACKAGE SN74LVC574A . . . DB. DW. OR PW PACKAGE

(TOP VIEW)

OE

1D 2

2D 🛛 3

8D 🛛 9

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20 VCC

19 1Q

18 2Q

12 8Q

- *EPIC*[™] (Enhanced-Performance Implanted CMOS) Submicron Process
- Typical V_{OLP} (Output Ground Bounce) < 0.8 V at V_{CC} = 3.3 V, $T_A = 25^{\circ}C$
- Typical V_{OHV} (Output V_{OH} Undershoot)
 > 2 V at V_{CC} = 3.3 V, T_A = 25°C
- Support Mixed-Mode Signal Operation on All Ports (5-V Input/Output Voltage With 3.3-V V_{CC})
- Power Off Disables Outputs, Permitting Live Insertion
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and DIPs (J)

description

The SN54LVC574A octal edge-triggered D-type flip-flop is designed for 2.7-V to 3.6-V V_{CC} operation and the SN74LVC574A octal edge-triggered D-type flip-flop is designed for 1.65-V to 3.6-V V_{CC} operation.

These devices feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

On the positive transition of the clock (CLK) input, the Q outputs are set to the logic levels at the data (D) inputs.

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

OE does not affect the internal operations of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.



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3D 🚺 4	17 🛛 3Q
3D [] 4 4D [] 5	16 🛛 4Q
5D 🛿 6	15 🛛 5Q
6D 🛛 7	14 🛛 6Q
5D [6 6D [7 7D [8	17] 3Q 16] 4Q 15] 5Q 14] 6Q 13] 7Q

GND 10 11 CLK

SN54LVC574A . . . FK PACKAGE (TOP VIEW)

	20 0 <u>6</u> 10 10	
	- < 0 - 10	
3D	3 2 1 20 19 4 18 2	2Q
3D 4D 5D 6D 7D	5 17 🖸 3	2Q 3Q 1Q
5D] 6 16[4	lQ
6D]7 15[]5	5Q
7D	8 10 11 10 10 10	SQ
	9 10 11 12 13	
	A C C C C C C C C C C C C C C C C C C C	
	- 6 0 ° ''	

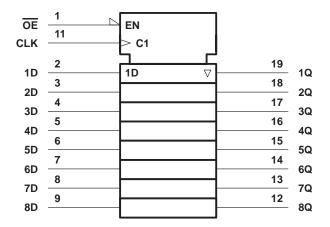
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description (continued)

The SN54LVC574A is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74LVC574A is characterized for operation from -40°C to 85°C.

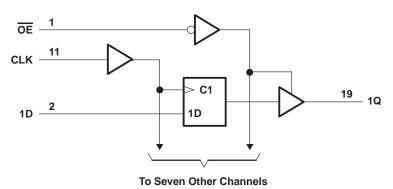
	FUNCTION TABLE (each flip-flop)										
	INPUTS OUTPUT										
OE	CLK	Q									
L	\uparrow	Н	Н								
L	\uparrow	L	L								
L	L	Х	Q ₀								
Н	Х	Х	z								

logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V _{CC} Input voltage range, V _I (see Note 1)	
Voltage range applied to any output in the high-impedance or power-off state, V_O	
(see Note 1)	–0.5 V to 6.5 V
Voltage range applied to any output in the high or low state, V _O	
(see Notes 1 and 2)	\dots –0.5 V to V _{CC} + 0.5 V
Input clamp current, I_{IK} (V _I < 0)	
Output clamp current, I _{OK} (V _O < 0)	
Continuous output current, I _O	±50 mA
Continuous current through V_{CC} or GND	±100 mA
Package thermal impedance, θ_{JA} (see Note 3): DB package	115°C/W
DW package	
PW package	128°C/W
Storage temperature range, T _{stg}	–65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The value of V_{CC} is provided in the recommended operating conditions table.

3. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 4)

			SN54L	VC574A	SN74L	/C574A	LINUT	
			MIN MAX		MIN	MAX	UNIT	
\/	Currente und the sec	Operating	2	3.6	1.65	3.6	V	
VCC	Supply voltage	Data retention only	1.5		1.5		V	
		V _{CC} = 1.65 V to 1.95 V			$0.65 \times V_{CC}$			
VIH	High-level input voltage	V_{CC} = 2.3 V to 2.7 V			1.7		V	
		V _{CC} = 2.7 V to 3.6 V	2		2			
		V _{CC} = 1.65 V to 1.95 V				$0.35 \times V_{CC}$		
VIL	Low-level input voltage	V _{CC} = 2.3 V to 2.7 V				0.7	V	
		V _{CC} = 2.7 V to 3.6 V		0.8		0.8		
VI	Input voltage		0	5.5	0	5.5	V	
.,		High or low state	0	VCC	0	VCC	V	
VO	Output voltage	3 state	0	5.5	0	5.5	V	
		V _{CC} = 1.65 V				-4		
1	Lich lovel output output	V _{CC} = 2.3 V				-8	A	
ЮН	High-level output current	V _{CC} = 2.7 V		-12		-12	mA	
		$V_{CC} = 3 V$		-24		-24		
		V _{CC} = 1.65 V				4		
1		V _{CC} = 2.3 V				8	A	
IOL	Low-level output current	$V_{CC} = 2.7 V$		12		12	mA	
		$V_{CC} = 3 V$		24		24		
$\Delta t/\Delta v$	Input transition rise or fall rate		0	6	0	6	ns/V	
TA	Operating free-air temperature		-55	125	-40	85	°C	

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	TEST CONDIT			SN54	4LVC574	A	SN74	LVC574	4	UNI	
PARAMETER	TEST CONDIT	IONS	Vcc	MIN	TYP†	MAX	MIN	TYP†	MAX		
	100.04		1.65 V to 3.6 V				V _{CC} -0.2				
	I _{OH} = -100 μA		2.7 V to 3.6 V	V _{CC} -0.2							
	I _{OH} = -4 mA		1.65 V				1.2				
VOH	IOH =8 mA		2.3 V				1.7			V	
	lou - 12 mA		2.7 V	2.2			2.2				
	I _{OH} = -12 mA		3 V	2.4			2.4				
	I _{OH} = -24 mA		3 V	2.2			2.2				
	100		1.65 V to 3.6 V						0.2		
	I _{OL} = 100 μA		2.7 V to 3.6 V			0.2				V	
Va	I _{OL} = 4 mA I _{OL} = 8 mA I _{OL} = 12 mA		1.65 V						0.45		
VOL			2.3 V						0.7		
			2.7 V			0.4			0.4		
	I _{OL} = 24 mA	I _{OL} = 24 mA				0.55			0.55		
lj	$V_{I} = 0$ to 5.5 V		3.6 V			±5			±5	μA	
Ioff	$V_{I} \text{ or } V_{O} = 5.5 \text{ V}$		0						±10	μA	
IOZ	V _O = 0 to 5.5 V		3.6 V			±15			±10	μA	
	$V_{I} = V_{CC} \text{ or } GND$		0.01/			10			10		
ICC	$3.6 \text{ V} \leq \text{V}_{I} \leq 5.5 \text{ V}^{\ddagger}$	IO = 0	3.6 V			10			10	μA	
ΔICC	One input at $V_{CC} - 0$. Other inputs at V_{CC} o		2.7 V to 3.6 V			500			500	μA	
Ci	$V_{I} = V_{CC} \text{ or } GND$		3.3 V		4			4		pF	
Co	$V_{O} = V_{CC} \text{ or } GND$		3.3 V		5.5			5.5		pF	

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

[‡] This applies in the disabled state only.

timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

			UNIT			
		SN54LVC574A V _{CC} = 2.7 V V _{CC} = 3.3 V ± 0.3 V MIN MAX MIN MAX 150 150 150 3.3 3.3 2 2 2 2 2 2				
		MIN	MAX	MIN	MAX	
fclock	Clock frequency		150		150	MHz
tw	Pulse duration, CLK high or low	3.3		3.3		ns
t _{su}	Setup time, data before CLK [↑]	2		2		ns
t _h	Hold time, data after CLK \uparrow	2		2		ns



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timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

	SN74LVC574A									
		V _{CC} = ± 0.1	1.8 V 5 V	V _{CC} = ± 0.	2.5 V 2 V	V _{CC} =	2.7 V	V _{CC} = ± 0.3	3.3 V 3 V	UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
fclock	Clock frequency		†		†		150		150	MHz
tw	Pulse duration, CLK high or low	†		†		3.3		3.3		ns
t _{su}	Setup time, data before CLK [↑]	†		†		2		2		ns
th	Hold time, data after CLK↑	†		†		1.5		1.5		ns

[†] This information was not available at the time of publication.

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

				SN54LV	/C574A		
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} =	2.7 V	= V _{CC} ± 0.3	3.3 V 3 V	UNIT
			MIN	MAX	MIN	MAX	
f _{max}			150		150		MHz
^t pd	CLK	Q		8	1	7	ns
t _{en}	OE	Q		9	1	7.5	ns
^t dis	OE	Q		7	0.5	6.4	ns

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

						SN74L\	/C574A				
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = ± 0.1		= V _{CC} ± 0.1	2.5 V 2 V	V _{CC} =	2.7 V	= V _{CC} ± 0.3	3.3 V 3 V	UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
fmax			†		†		150		150		MHz
^t pd	CLK	Q	†	†	†	†		8	2.2	7	ns
t _{en}	OE	Q	+	†	+	†		8.5	1.5	7.5	ns
^t dis	OE	Q	†	†	†	†		7	1.7	6.4	ns
^t sk(o) [‡]										1	ns

[†] This information was not available at the time of publication.

[‡] Skew between any two outputs of the same package switching in the same direction

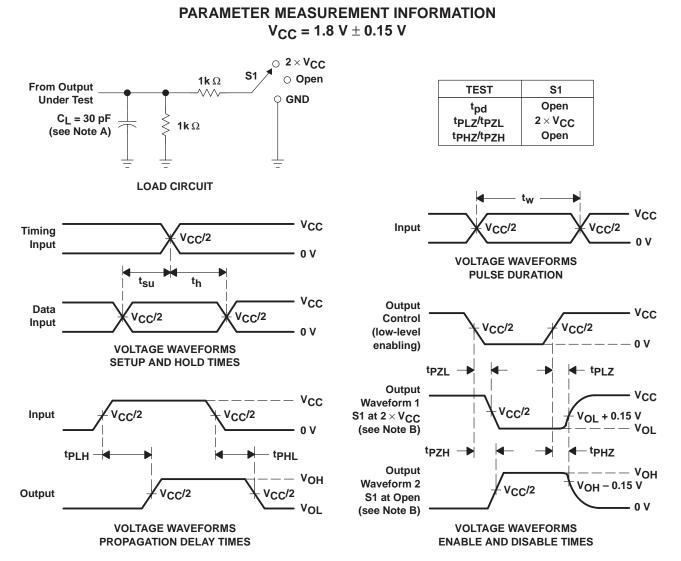
operating characteristics, T_A = 25°C

	PARAMETER	TEST CONDITIONS	V _{CC} = 1.8 V ± 0.15 V	$\begin{array}{c} \text{V}_{\text{CC}} = 2.5 \text{ V} \\ \pm 0.2 \text{ V} \end{array}$	$\begin{array}{c} \text{V}_{\text{CC}} = 3.3 \text{ V} \\ \pm 0.3 \text{ V} \end{array}$	UNIT	
			CONDITIONS		TYP	TYP	
Cpd	Power dissipation capacitance	Outputs enabled	£ 40 MU	†	†	43	pF
Cpa	per flip-flop	Outputs disabled	f = 10 MHz	†	†	15	рг

[†] This information was not available at the time of publication.



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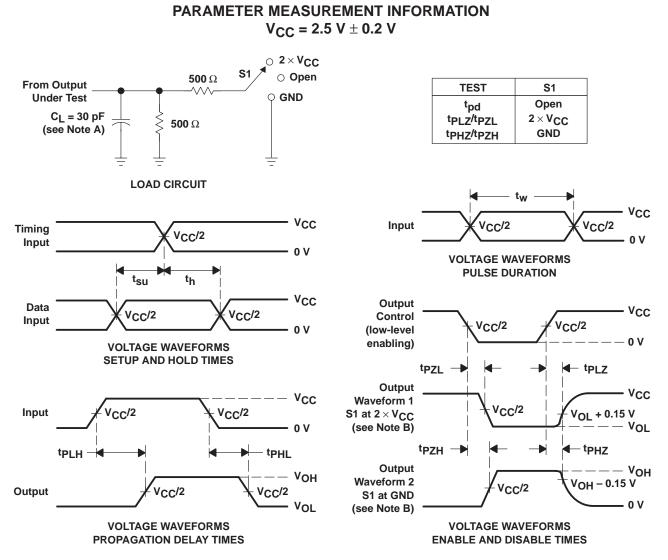


- NOTES: A. CL includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_Q = 50 Ω, t_f ≤ 2 ns, t_f ≤ 2 ns.
 - C. An input pulses are supplied by generators having the following characteristics. Fix ≤ 10 win 2, 20 = 30.32, $t_{f} \leq 2$ hs, $t_{f} \leq 2$
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. tPLH and tPHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms



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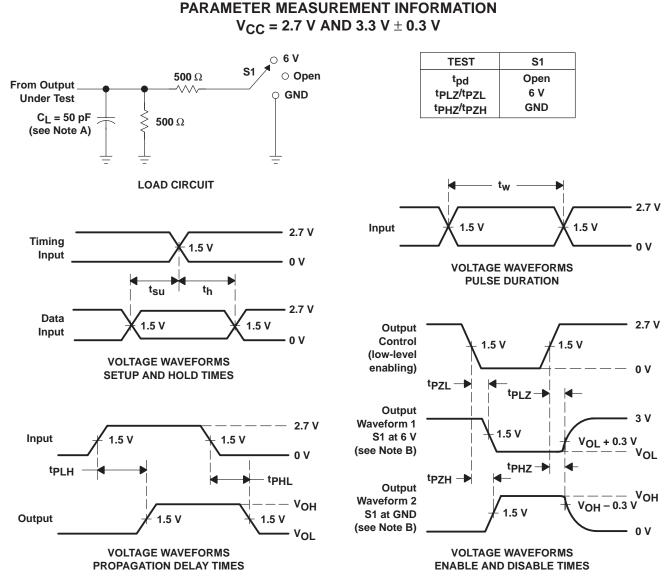


- NOTES: A. CL includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_f ≤ 2 ns, t_f ≤ 2 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - D. The outputs are measured one at a time with one train
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. tPLH and tPHL are the same as tpd.

Figure 2. Load Circuit and Voltage Waveforms



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- NOTES: A. C_I includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_Q = 50 Ω , t_f \leq 2.5 ns, t_f \leq 2.5 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tPLZ and tPHZ are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tPLH and tPHL are the same as tpd.

Figure 3. Load Circuit and Voltage Waveforms



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